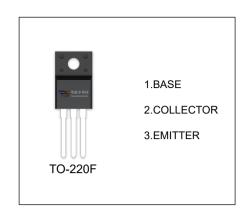


KTA1659 TRANSISTOR (PNP)

FEATURES

- High Transition Frequency
- High Voltage Applications



MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

| Symbol | Parameter | Value | Unit |
|----------------------------------|--|----------|------------|
| V _{CBO} | Collector-Base Voltage | -160 | V |
| V _{CEO} | V _{CEO} Collector-Emitter Voltage | | V |
| V _{EBO} | Emitter-Base Voltage | -5 | V |
| Ic | Collector Current | -1.5 | Α |
| Pc | Collector Power Dissipation | 2 | W |
| R _{θJA} | R _{0JA} Thermal Resistance From Junction To Ambient | | °C/W |
| T _J ,T _{stg} | Operation Junction and Storage Temperature Range | -55~+150 | $^{\circ}$ |

ELECTRICAL CHARACTERISTICS (T_a =25 $^{\circ}$ C unless otherwise specified)

| Parameter | Symbol | Test conditions | Min | Тур | Max | Unit |
|---|----------------------|---|------|-----|------|------|
| Collector-base breakdown voltage | V _{(BR)CBO} | I _C =-100μΑ,I _E =0 | -160 | | | V |
| Collector-emitter breakdown voltage | V _{(BR)CEO} | I _C =-10mA,I _B =0 | -160 | | | V |
| Emitter-base breakdown voltage | V _{(BR)EBO} | I _E =-1mA,I _C =0 | -5 | | | V |
| Collector cut-off current I _{CBO} V _{CB} =-160V,I _E =0 | | | | -1 | μA | |
| Emitter cut-off current | I _{EBO} | V _{EB} =-5V,I _C =0 | | | -1 | μA |
| DC current gain | h _{FE} | V _{CE} =-5V, I _C =-100mA | 70 | | 240 | |
| Collector-emitter saturation voltage | V _{CE(sat)} | I _C =-500mA,I _B =-50mA | | | -1.5 | V |
| Base-emitter voltage | V _{BE} | V _{CE} =-5V, I _C =-500mA | | | -1 | V |
| Collector output capacitance | C _{ob} | V _{CB} =-10V,I _E =0, f=1MHz | | 30 | | pF |
| Transition frequency | f _T | Vce=-10V,Ic=-100mA | | 100 | · | MHz |

CLASSIFICATION OF h_{FE}

| RANK | 0 | Y | | | |
|-------|--------|---------|--|--|--|
| RANGE | 70-140 | 120-240 | | | |